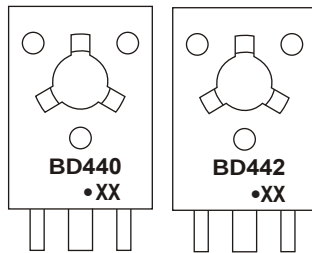


**TO-126 Plastic-Encapsulate Transistors****BD440 / BD442** TRANSISTOR (PNP)**FEATURES**

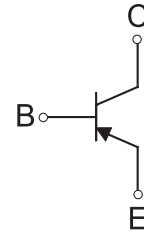
- Amplifier and Switching Applications
- Complement To BD439, BD441

TO - 126

1. EMITTER
2. COLLECTOR
3. BASE

**MARKING**

BD440,BD442=Device code
Solid dot = Green molding compound device, if none, the normal device
XX=Code

Equivalent Circuit**ORDERING INFORMATION**

Part Number	Package	Packing Method	Pack Quantity
BD440	TO-126	Bulk	200pcs/Bag
BD442	TO-126	Bulk	200pcs/Bag
BD440-TU	TO-126	Tube	60pcs/Tube
BD442-TU	TO-126	Tube	60pcs/Tube

MAXIMUM RATINGS($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	BD440	-60
		BD442	-80
V_{CEO}	Collector-Emitter Voltage	BD440	-60
		BD442	-80
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current –Continuous	-4	A
P_C	Collector Power Dissipation	1.25	W
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55-150	$^{\circ}\text{C}$

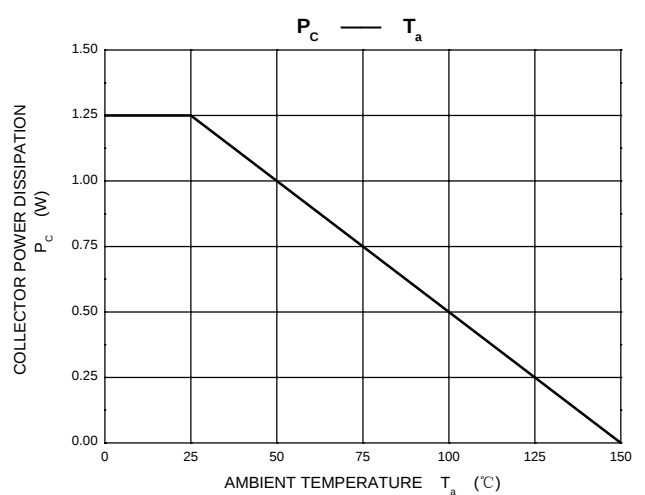
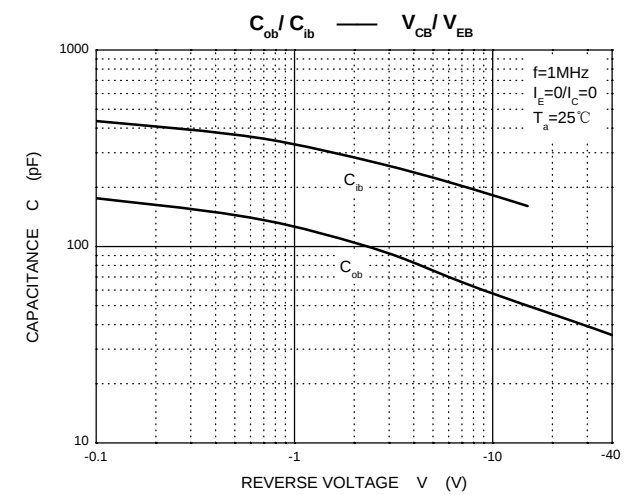
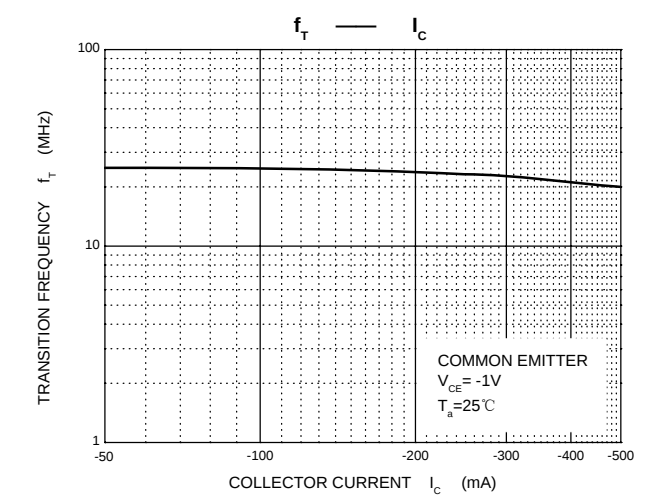
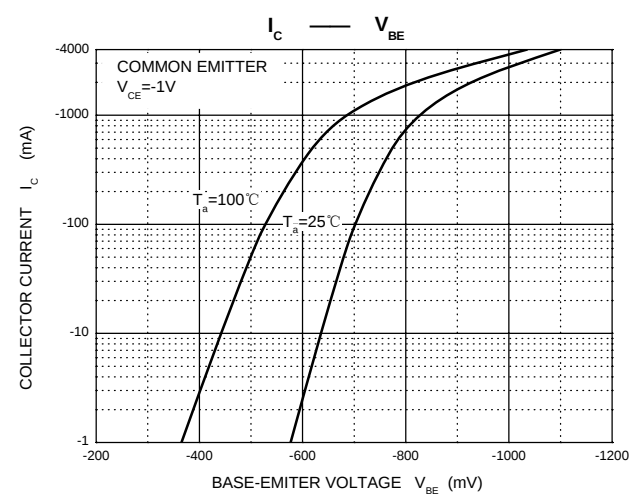
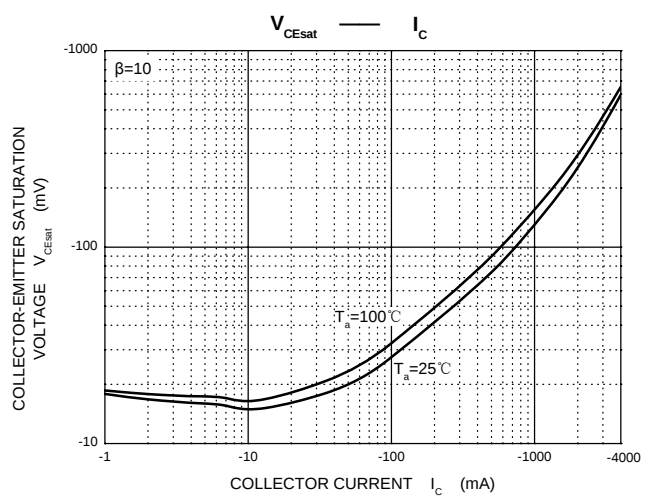
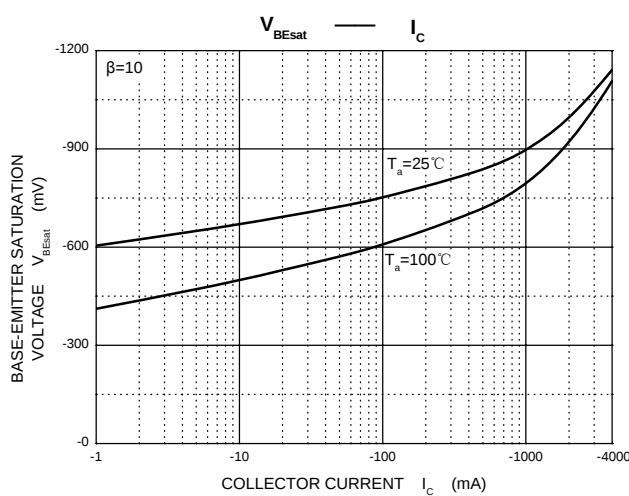
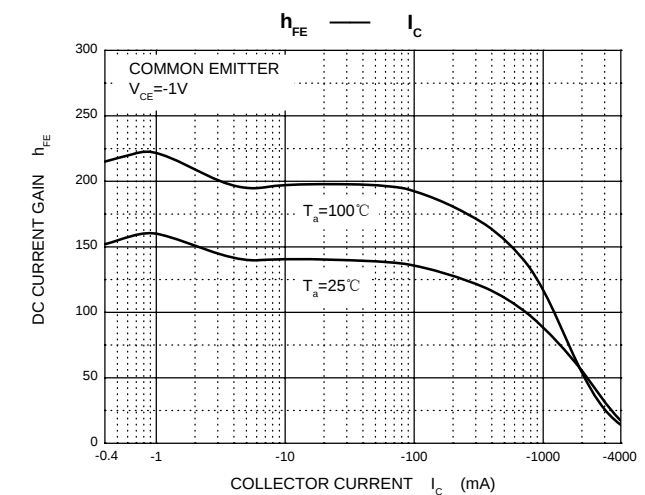
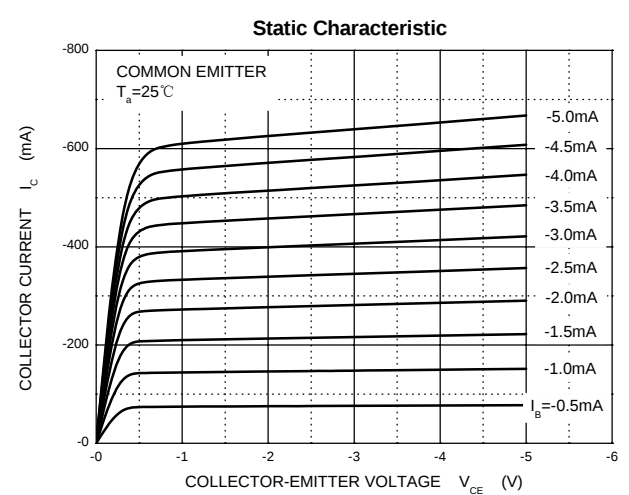
ELECTRICAL CHARACTERISTICS

$T_a = 25^\circ\text{C}$

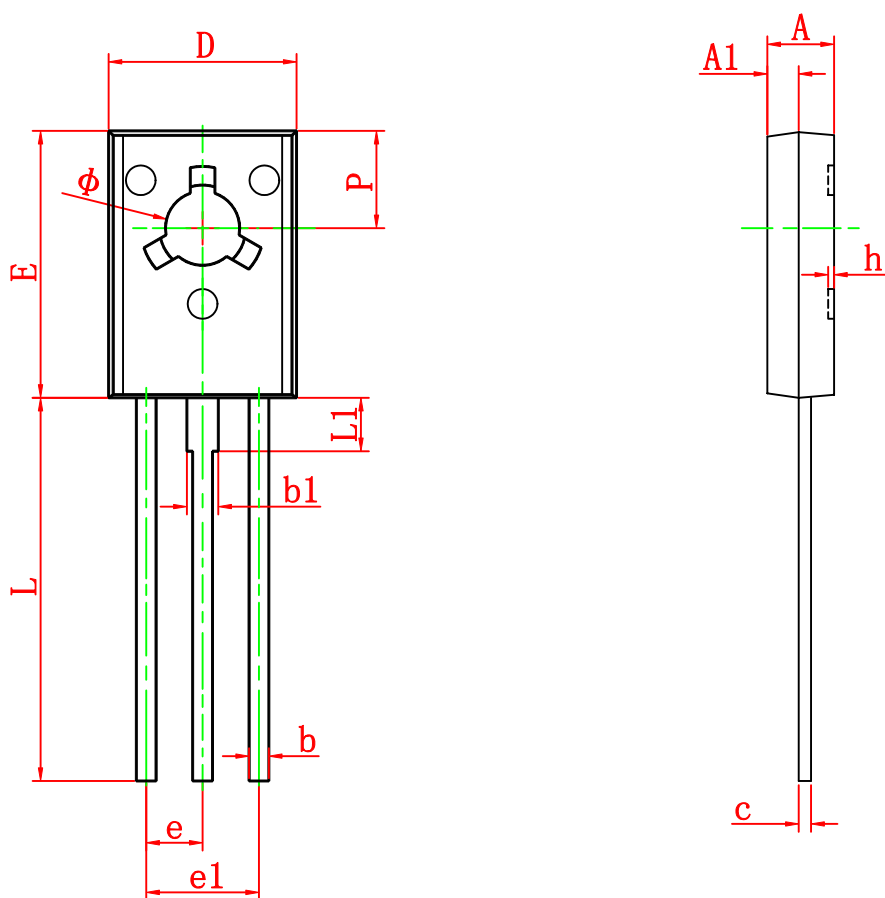
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -100\mu\text{A}, I_E = 0$ BD440 BD442	-60 -80			V
Collector-emitter breakdown voltage	$V_{CEO(SUS)}^{(1)}$	$I_C = -100\text{mA}, I_B = 0$ BD440 BD442	-60 -80			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -100\mu\text{A}, I_C = 0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB} = -60\text{V}, I_E = 0$ $V_{CB} = -80\text{V}, I_E = 0$ BD440 BD442			-100	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -5\text{V}, I_E = 0$			-1	mA
DC current gain	$h_{FE(1)}^{(1)}$	$V_{CE} = -1\text{V}, I_C = -500\text{mA}$	40		475	
	$h_{FE(2)}^{(1)}$	$V_{CE} = -5\text{V}, I_C = -10\text{mA}$ BD440 BD442	20 15			
	$h_{FE(3)}^{(1)}$	$V_{CE} = -1\text{V}, I_C = -2\text{A}$ BD440 BD442	25 15			
Collector-emitter saturation voltage	$V_{CE(sat)}^{(1)}$	$I_C = -3\text{A}, I_B = -0.3\text{A}$			-0.8	V
Base-emitter voltage	$V_{BE}^{(1)}$	$V_{CE} = -1\text{V}, I_C = -2\text{A}$			-1.5	V
Transition frequency	f_T	$V_{CE} = -1\text{V}, I_C = -250\text{mA}$	3			MHz

⁽¹⁾Pulse test

Typical Characteristics



TO-126 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	2.500	2.900	0.098	0.114
A1	1.100	1.500	0.043	0.059
b	0.660	0.860	0.026	0.034
b1	1.170	1.370	0.046	0.054
c	0.450	0.600	0.018	0.024
D	7.400	7.800	0.291	0.307
E	10.600	11.000	0.417	0.433
e	2.290 TYP		0.090 TYP	
e1	4.480	4.680	0.176	0.184
h	0.000	0.300	0.000	0.012
L	15.300	15.700	0.602	0.618
L1	2.100	2.300	0.083	0.091
P	3.900	4.100	0.154	0.161
Φ	3.000	3.200	0.118	0.126